NSN 5961-01-480-6215

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-6215 **Inclosure Material:** Ceramic **Overall Length:** 5.350 millimeters **Overall Height:** 8.220 millimeters **Overall Width:** 2.300 millimeters **End Application:** Stv camera sy **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 3.30 amperes forward current, average **Capacitance Rating In Picofarads:** 110.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction and -40.0 degrees celsius junction **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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